

L Number	Hits	Search Text	DB	Time stamp
13	26	(negative adj resistance) near9 npn	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/21 16:29
14	3	(negative adj resistance) near9 (transistor diode) near9 amp	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/21 16:32
16	0	((negative adj resistance) near9 (transistor diode) near9 current) near9 ((gas adj insulating adj apparatus) adj ampere)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/21 16:33
17	0	((negative adj resistance) near9 (transistor diode) near9 current) near9 (one adj ampere)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/21 16:33
15	334	(negative adj resistance) near9 (transistor diode) near9 current	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/21 16:46
18	0	20030071676.URPN.	USPAT	2004/04/21 16:36
19	28724	power adj (transistors diodes)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/21 16:47
20	0	(power adj (transistors diodes)) near9 (negative adj resistance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/21 16:47